AR/ARS35X SERIES HIGH CURRENT PLASTIC SILICON RECTIFIER

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AR/ARS35005 THRU AR/ARS3510

HIGH CURRENT PLASTIC SILICON RECTIFIER



REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 35.0 AMPERE

FEATURES

· Plastic material has Underwriters Laboratory Flammability Classification 94V-0

- · Low cost construction utilizing void-free molded plastic technique
- · Low cost
- · Diffused junction
- · High surge current capability
- · Low leakage
- · High temperature soldering guaranteed: 250°C for 10 seconds

MECHANICAL DATA

Case: Molded plastic, RA/RAS

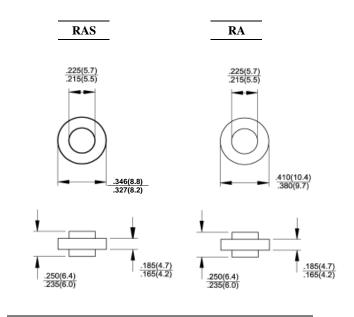
Epoxy: UL 94V-O rate flame retardant

Lead: Axial leads, solderable per MIL-STD-202,

method 208 guaranteed

Polarity: Color ring denotes cathode end

Mounting position: Any Weight: 0.07ounce, 1.8gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at $25\,^\circ\!\!\!\!\!\mathrm{C}$ ambient temperature unless otherwise specified.

Single phase, half wave, $60H_Z$, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	AR35005	AR3501	AR3502	AR3504	AR3506	AR3508	AR3510	Units
		ARS35005	ARS3501	ARS3502	ARS3504	ARS3506	ARS3508	ARS3510	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T _C =150 ℃	$I_{(AV)}$	35							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	500							Amp
Maximum Forward Voltage at 35.0A DC and 25℃	$\mathbf{V_F}$	1.0							Volts
Maximum Reverse Current at T_C =25 °C at Rated DC Blocking Voltage T_C =100 °C	I_R	5.0 250							uAmp
Typical Junction Capacitance (Note 1)	C_{J}	300							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	1							°C/W
Maximum Reverse Recovery Time (Note 3)	T_{RR}	3							uS
Operating and Storage Temperature Range	T _J , Tstg	-55 to +175							င

NOTES:

- 1- Measured at 1 MH_Z and applied reverse voltage of 4.0 VDC.
- 2- Reverse Recovery Test Conditions: I_F =.5A, I_R =1A, I_{RR} =.25A.
- 3- Thermal Resistance from Junction to Case, Singe Side Cooled.

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RATINGS AND CHARACTERISTIC CURVES

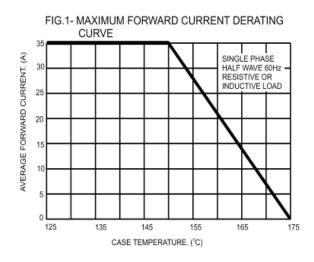


FIG.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

1000

8.3ms Single Half Sine Wave JEDEC Method

1000

100

NUMBER OF CYCLES AT 60Hz

FIG.3- TYPICAL FORWARD CHARACTERISTICS

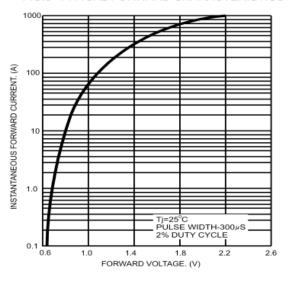


FIG.4- TYPICAL REVERSE CHARACTERISTICS

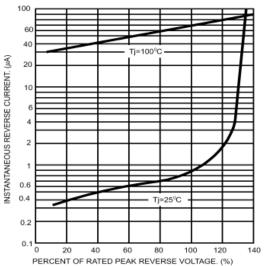


FIG.5- TYPICAL JUNCTION CAPACITANCE

